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Kind regards,

Team Nexperia

# PESD3V3L1UA; PESD3V3L1UB; PESD3V3L1UL

Low capacitance unidirectional ESD protection diodes

Rev. 01 — 17 June 2009

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

Low capacitance unidirectional ElectroStatic Discharge (ESD) protection diodes in small Surface-Mounted Device (SMD) plastic packages designed to protect one signal line from the damage caused by ESD and other transients.

Table 1. Product overview

Type number	Package		Package configuration	
	NXP	JEITA		
PESD3V3L1UA	SOD323	SC-76	very small	
PESD3V3L1UB	SOD523	SC-79	ultra small and flat lead	
PESD3V3L1UL	SOD882	-	leadless ultra small	

#### 1.2 Features

- Unidirectional ESD protection of one line
- Low diode capacitance: C<sub>d</sub> = 34 pF
- Low clamping voltage: V<sub>CL</sub> = 11 V
- Very low leakage current: I<sub>RM</sub> = 100 nA
- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- AEC-Q101 qualified

### 1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Communication systems
- Subscriber Identity Module (SIM) card protection
- Portable electronics
- FireWire
- High-speed data lines

#### 1.4 Quick reference data

Table 2. Quick reference data

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RWM}$	reverse standoff voltage		-	-	3.3	V
$C_d$	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	34	40	pF



Low capacitance unidirectional ESD protection diodes

#### **Pinning information** 2.

Table 3. **Pinning** 

Table 5.			
Pin	Description	Simplified outline	Graphic symbol
PESD3V3	BL1UA; PESD3V3L1UB		
1	cathode	[1]	
2	anode	001aab540	1 2 2
PESD3V3	BL1UL		
1	cathode	[1]	
2	anode	Transparent top view	1 2 006aaa152

<sup>[1]</sup> The marking bar indicates the cathode.

#### **Ordering information** 3.

**Ordering information** Table 4.

Type number	Package				
	Name	Description	Version		
PESD3V3L1UA	SC-76	plastic surface-mounted package; 2 leads	SOD323		
PESD3V3L1UB	SC-79	plastic surface-mounted package; 2 leads	SOD523		
PESD3V3L1UL	-	leadless ultra small plastic package; 2 terminals; body $1.0\times0.6\times0.5$ mm	SOD882		

# **Marking**

**Product data sheet** 

Table 5. **Marking codes** 

3	
Type number	Marking code
PESD3V3L1UA	1H
PESD3V3L1UB	Z7
PESD3V3L1UL	XW

2 of 13

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#### Low capacitance unidirectional ESD protection diodes

## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$P_{PP}$	peak pulse power	$t_p = 8/20 \; \mu s$	[1][2]	45	W
$I_{PP}$	peak pulse current	$t_p = 8/20 \; \mu s$	[1][2]	4.5	Α
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		<b>–55</b>	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

Table 7. ESD maximum ratings

T<sub>amb</sub> = 25 °C unless otherwise specified.

	•					
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>ESD</sub> electrostatic discharge voltage	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	<u>[1]</u>	-	30	kV
	machine model		-	400	V	
	MIL-STD-883 (human body model)		-	10	kV	

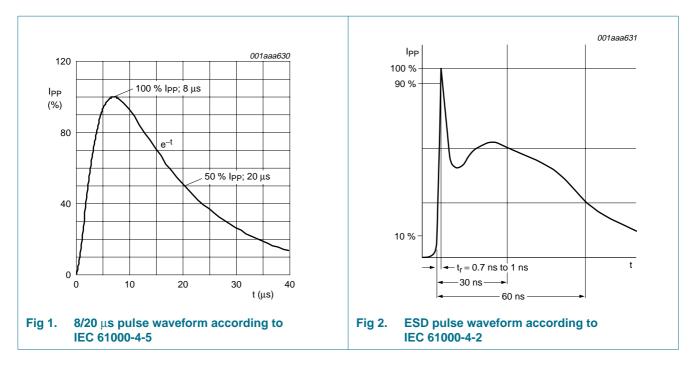
<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.

#### Table 8. ESD standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

<sup>[2]</sup> Measured from pin 1 to pin 2.

#### Low capacitance unidirectional ESD protection diodes



#### 6. Characteristics

Table 9. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Mi	n Ty	o Max	Unit
$V_{RWM}$	reverse standoff voltage		-	-	3.3	V
$I_{RM}$	reverse leakage current	$V_{RWM} = 3.3 V$	-	100	300	nA
$V_{BR}$	breakdown voltage	$I_R = 5 \text{ mA}$	5.3	5.6	6.0	V
C <sub>d</sub>	diode capacitance	f = 1 MHz; $V_R = 0 V$	-	34	40	pF
$V_{CL}$	clamping voltage		[1][2]			
		$I_{PP} = 1 A$	-	-	8	V
		$I_{PP} = 4.5 A$	-	-	11	V
$r_{dif}$	differential resistance	$I_R = 5 \text{ mA}$	-	-	30	Ω
$V_{F}$	forward voltage	$I_F = 200 \text{ mA}$	-	-	1.2	V

<sup>[1]</sup> Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

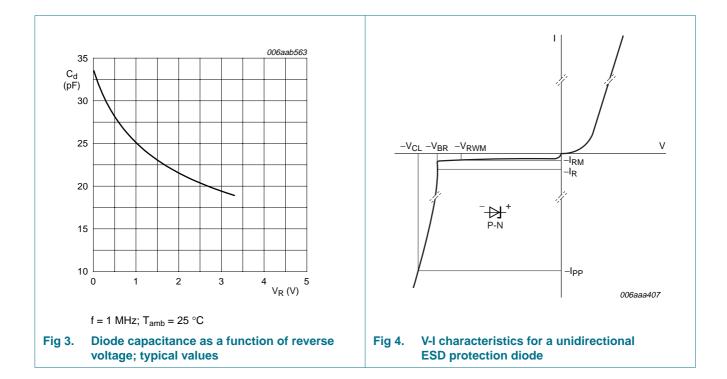
<sup>[2]</sup> Measured from pin 1 to pin 2.

**Product data sheet** 

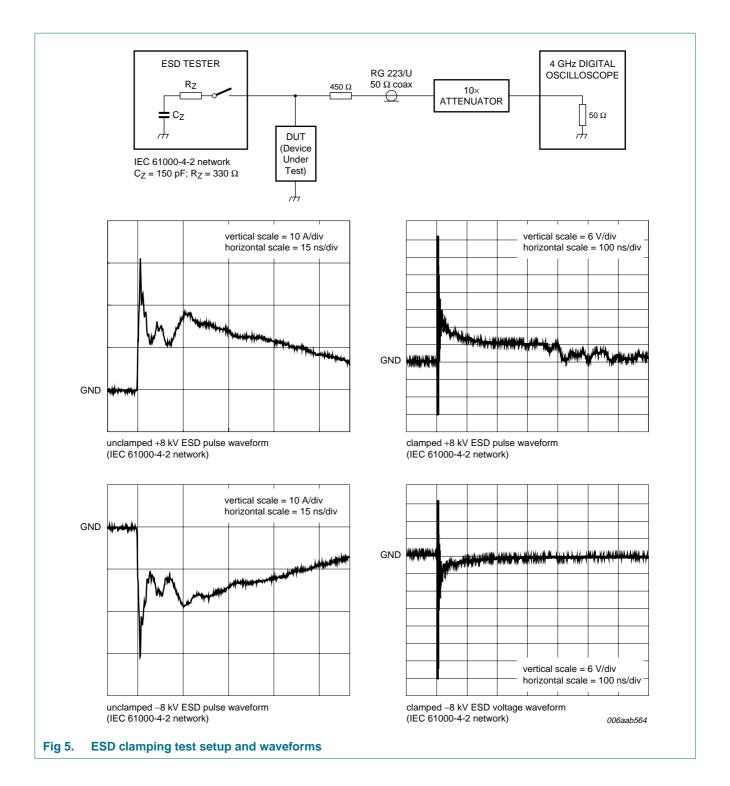
# PESD3V3L1UA/UB/UL

5 of 13

#### Low capacitance unidirectional ESD protection diodes



#### Low capacitance unidirectional ESD protection diodes

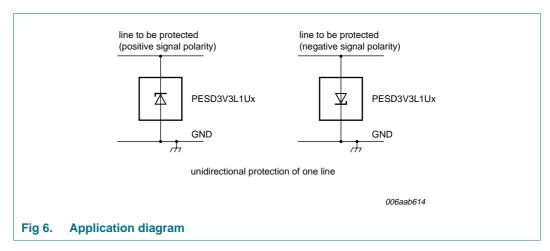


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Low capacitance unidirectional ESD protection diodes

## 7. Application information

The PESD3V3L1Ux series is designed for the protection of one unidirectional data or signal line from the damage caused by ESD and surge pulses. The devices may be used on lines where the signal polarities are either positive or negative with respect to ground. The PESD3V3L1Ux series provides a surge capability up to 45 W per line for an 8/20  $\mu s$  waveform.



#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD and Electrical Fast Transient (EFT). The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

#### 8. Test information

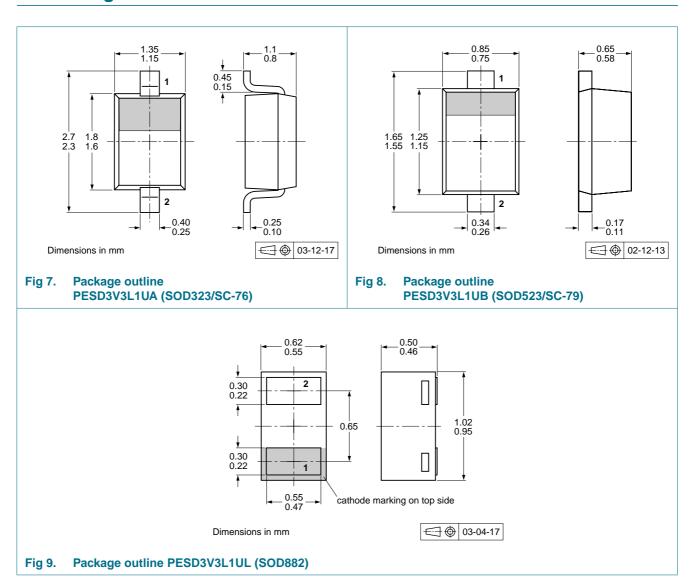
#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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Low capacitance unidirectional ESD protection diodes

## **Package outline**



# 10. Packing information

**Product data sheet** 

Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packin	Packing quantity		
			3000	8000	10000	
PESD3V3L1UA	SOD323	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PESD3V3L1UB SOD523		2 mm pitch, 8 mm tape and reel	-	-315	-	
		4 mm pitch, 8 mm tape and reel	-115	-	-135	
PESD3V3L1UL	SOD882	2 mm pitch, 8 mm tape and reel	-	-	-315	

8 of 13

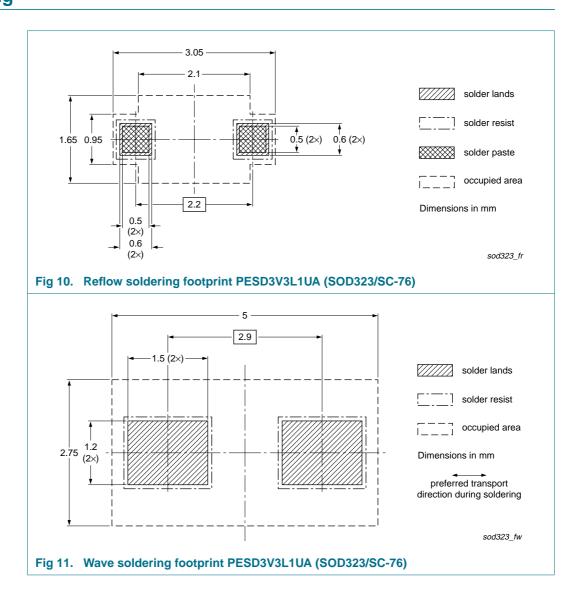
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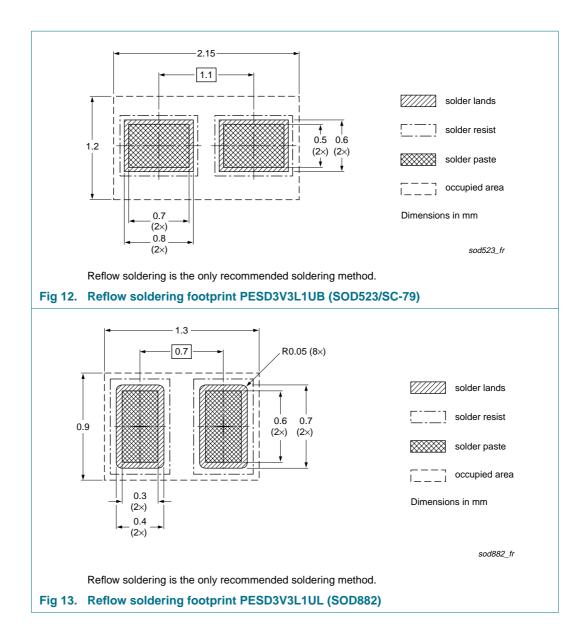
<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

#### Low capacitance unidirectional ESD protection diodes

## 11. Soldering



#### Low capacitance unidirectional ESD protection diodes



Low capacitance unidirectional ESD protection diodes

# 12. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD3V3L1UA_UB_UL_1	20090617	Product data sheet	-	-

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 Product data sheet
 Rev. 01 − 17 June 2009
 11 of 13

#### Low capacitance unidirectional ESD protection diodes

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### Low capacitance unidirectional ESD protection diodes

## 15. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications
1.4	Quick reference data
2	Pinning information 2
3	Ordering information
4	Marking 2
5	Limiting values 3
6	Characteristics 4
7	Application information 7
8	Test information
8.1	Quality information
9	Package outline 8
10	Packing information 8
11	Soldering 9
12	Revision history 11
13	Legal information 12
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks12
14	Contact information 12
15	Contents

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